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# 74HC4066; 74HCT4066

# Quad single-pole single-throw analog switch Rev. 7 — 2 April 2013

**Product data sheet** 

#### 1. **General description**

The 74HC4066; 74HCT4066 is a quad single pole, single throw analog switch. Each switch features two input/output terminals (nY and nZ) and an active HIGH enable input (nE). When nE is LOW, the analog switch is turned off. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of  $V_{CC}$ .

#### **Features and benefits** 2.

- Input levels nE inputs:
  - ◆ For 74HC4066: CMOS level
  - ◆ For 74HCT4066: TTL level
- Low ON resistance:
  - 50  $\Omega$  (typical) at  $V_{CC} = 4.5 \text{ V}$
  - 45  $\Omega$  (typical) at  $V_{CC} = 6.0 \text{ V}$
  - 35  $\Omega$  (typical) at  $V_{CC} = 9.0 \text{ V}$
- Specified in compliance with JEDEC standard no. 7A
- ESD protection:
  - ◆ HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

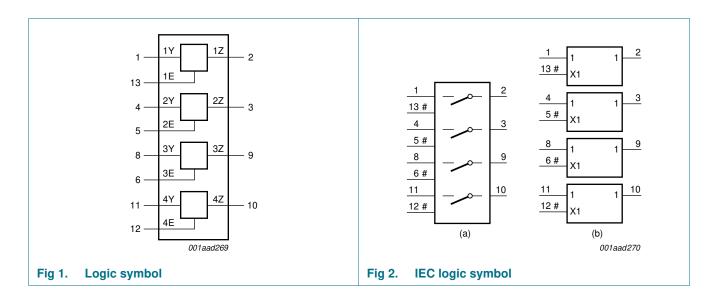


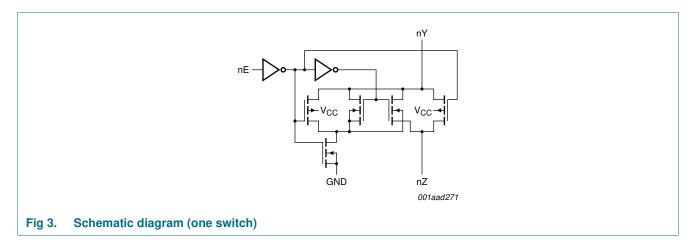
### 3. Ordering information

Table 1. Ordering information

Type number	Package				
	Temperature range	Name	Description	Version	
74HC4066N	–40 °C to +125 °C	DIP14	plastic dual in-line package; 14 leads (300 mil)	SOT27-1	
74HCT4066N					
74HC4066D	–40 °C to +125 °C	SO14	plastic small outline package; 14 leads; body width	SOT108-1	
74HCT4066D			3.9 mm		
74HC4066DB	–40 °C to +125 °C	SSOP14	plastic shrink small outline package; 14 leads; body	SOT337-1	
74HCT4066DB			width 5.3 mm		
74HC4066PW	–40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads; body	SOT402-1	
74HCT4066PW			width 4.4 mm		
74HC4066BQ	–40 °C to +125 °C	DHVQFN14	plastic dual in-line compatible thermal enhanced very	SOT762-1	
74HCT4066BQ	_		thin quad flat package; no leads; 14 terminals; body $2.5 \times 3 \times 0.85$ mm		

### 4. Functional diagram





### 5. Pinning information

### 5.1 Pinning

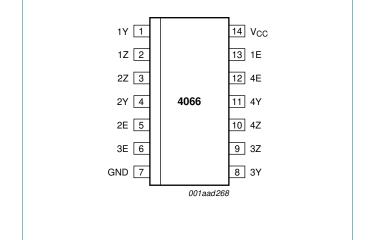
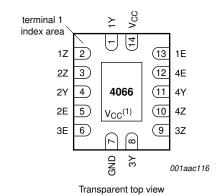


Fig 4. Pin configuration for DIP14, SO14, SSOP14 and TSSOP14



(1) This is not a supply pin. The substrate is attached to this pad using conductive die attach material. There is no electrical or mechanical requirement to solder this pad. However, if it is soldered, the solder land should remain floating or be connected to VCC.

Fig 5. Pin configuration for DHVQFN14

### 5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1Z, 2Z, 3Z, 4Z	2, 3, 9, 10	independent input or output
1Y, 2Y, 3Y, 4Y	1, 4, 8, 11	independent input or output
GND	7	ground (0 V)
1E, 2E, 3E, 4E	13, 5, 6, 12	enable input (active HIGH)
V <sub>CC</sub>	14	supply voltage

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### 6. Functional description

#### Table 3. Function table[1]

Input nE	Switch
L	OFF
Н	ON

<sup>[1]</sup> H = HIGH voltage level;

L = LOW voltage level.

### 7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+11.0	V
I <sub>IK</sub>	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I <sub>SK</sub>	switch clamping current	$V_{SW} < -0.5 \text{ V or } V_{SW} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I <sub>SW</sub>	switch current	$V_{SW} = -0.5 \text{ V to } V_{CC} + 0.5 \text{ V}$	<u>[1]</u> -	±25	mA
I <sub>CC</sub>	supply current		-	50	mA
I <sub>GND</sub>	ground current		-	-50	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$	[2]		
		DIP14 package		-	750
		SO14, (T)SSOP14 and DHVQFN14 packages		-	500
Р	power dissipation	per switch	-	100	mW

<sup>[1]</sup> To avoid drawing V<sub>CC</sub> current out of terminal Z, when switch current flows in terminals Yn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no V<sub>CC</sub> current will flow out of terminals Yn. In this case there is no limit for the voltage drop across the switch, but the voltages at Yn and Z may not exceed V<sub>CC</sub> or GND.

For SO14 package:  $P_{tot}$  derates linearly with 8 mW/K above 70 °C.

For (T)SSOP14 packages:  $P_{tot}$  derates linearly with 5.5 mW/K above 60  $^{\circ}\text{C}.$ 

For DHVQFN14 packages: Ptot derates linearly with 4.5 mW/K above 60 °C.

<sup>[2]</sup> For DIP14 package:  $P_{tot}$  derates linearly with 12 mW/K above 70 °C.

### **Recommended operating conditions**

Table 5. **Recommended operating conditions** 

Symbol	Parameter	Conditions	7	4HC406	6	74HCT4066			Unit
			Min	Тур	Max	Min	Тур	Max	
$V_{CC}$	supply voltage		2.0	5.0	10.0	4.5	5.0	5.5	V
V <sub>I</sub>	input voltage		GND	-	$V_{CC}$	GND	-	$V_{CC}$	V
$V_{SW}$	switch voltage		GND	-	$V_{CC}$	GND	-	$V_{CC}$	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise	$V_{CC} = 2.0 \text{ V}$	-	-	625	-	-	-	ns/V
	and fall rate	$V_{CC} = 4.5 \text{ V}$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 \text{ V}$	-	-	83	-	-	-	ns/V
		$V_{CC} = 10.0 \text{ V}$	-	-	35	-	-	-	ns/V

### Static characteristics

### R<sub>ON</sub> resistance per switch for types 74HC4066 and 74HCT4066

 $V_I = V_{IH}$  or  $V_{IL}$ ; for test circuit see <u>Figure 6</u>.

 $V_{is}$  is the input voltage at a Yn or  $\overline{Z}$  terminal, whichever is assigned as an input.

 $V_{os}$  is the output voltage at a Yn or Z terminal, whichever is assigned as an output. For 74HC4066:  $V_{CC}$  – GND = 2.0 V, 4.5 V, 6.0 V and 9.0 V. For 74HCT4066:  $V_{CC}$  – GND = 4.5 V.

Symbol	Parameter	Conditions		–40 °C to +85 °C			-40 °C to +125 °C		Unit
				Min	Typ[1]	Max	Min	Max	
R <sub>ON(peak)</sub>	ON resistance (peak)	$V_{is} = V_{CC}$ to GND							
		$V_{CC} = 2.0 \text{ V}; I_{SW} = 100  \mu\text{A}$	2]	-	-	-	-	-	Ω
		$V_{CC}$ = 4.5 V; $I_{SW}$ = 1000 $\mu A$		-	54	-	118	142	Ω
		$V_{CC}$ = 6.0 V; $I_{SW}$ = 1000 $\mu A$		-	42	-	105	126	Ω
		$V_{CC}$ = 9.0 V; $I_{SW}$ = 1000 $\mu A$		-	32	-	88	105	Ω
R <sub>ON(rail)</sub>	ON resistance (rail)	$V_{is} = GND$							
		$V_{CC} = 2.0 \text{ V}; I_{SW} = 100  \mu\text{A}$	2]	-	80	-	-	-	Ω
		$V_{CC}$ = 4.5 V; $I_{SW}$ = 1000 $\mu A$		-	35	-	95	115	Ω
		$V_{CC} = 6.0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	27	-	82	100	Ω
		$V_{CC}$ = 9.0 V; $I_{SW}$ = 1000 $\mu A$		-	20	-	70	85	Ω
		$V_{is} = V_{CC}$							
		$V_{CC} = 2.0 \text{ V}; I_{SW} = 100  \mu\text{A}$	2]	-	100	-	-	-	Ω
		$V_{CC}$ = 4.5 V; $I_{SW}$ = 1000 $\mu A$		-	42	-	106	128	Ω
		$V_{CC}$ = 6.0 V; $I_{SW}$ = 1000 $\mu A$		-	35	-	94	113	Ω
		$V_{CC} = 9.0 \text{ V}; I_{SW} = 1000 \ \mu\text{A}$		-	20	-	78	95	Ω

Table 6. R<sub>ON</sub> resistance per switch for types 74HC4066 and 74HCT4066 ...continued

 $V_I = V_{IH}$  or  $V_{IL}$ ; for test circuit see <u>Figure 6</u>.

 $V_{is}$  is the input voltage at a Yn or  $\overline{Z}$  terminal, whichever is assigned as an input.

Vos is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

For 74HC4066:  $V_{CC}$  – GND = 2.0 V, 4.5 V, 6.0 V and 9.0 V.

For 74HCT4066:  $V_{CC}$  – GND = 4.5 V.

Symbol	Parameter	Conditions	-40 °C to +85 °C			–40 °C to	Unit		
					Typ[1]	Max	Min	Max	
mis	ON resistance	$V_{is} = V_{CC}$ to GND							
	mismatch between channels	V <sub>CC</sub> = 2.0 V	[2]	-	-	-	-	-	Ω
	Chameis	V <sub>CC</sub> = 4.5 V		-	5	-	-	-	Ω
		$V_{CC} = 6.0 \text{ V}$		-	4	-	-	-	Ω
		V <sub>CC</sub> = 9.0 V		-	3	-	-	-	Ω

- [1] Typical values are measured at  $T_{amb} = 25 \, ^{\circ}C$ .
- [2] At supply voltages (V<sub>CC</sub> GND) approaching 2 V, the analog switch ON resistance becomes extremely non-linear. Therefore it is recommended that these devices be used to transmit digital signals only, when using these supply voltages.

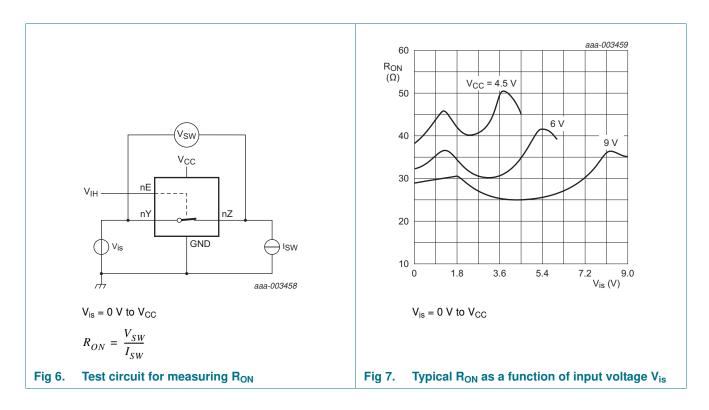


Table 7. Static characteristics 74HC4066

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).  $V_{is}$  is the input voltage at a Yn or Z terminal, whichever is assigned as an input.  $V_{os}$  is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
T <sub>amb</sub> = -40	0 °C to +85 °C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	٧
		V <sub>CC</sub> = 4.5 V	3.15	2.4	-	V
		$V_{CC} = 6.0 \text{ V}$	4.2	3.2	-	V
		$V_{CC} = 9.0 \text{ V}$	6.3	4.7	-	V
/ <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	8.0	0.5	V
		$V_{CC} = 4.5 \text{ V}$	-	2.1	1.35	V
		$V_{CC} = 6.0 \text{ V}$	-	2.8	1.80	V
		$V_{CC} = 9.0 \text{ V}$	-	4.3	2.70	V
I	input leakage current	$V_I = V_{CC}$ or GND				
		$V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μА
		V <sub>CC</sub> = 10.0 V	-	-	±2.0	μА
S(OFF)	OFF-state leakage current	$V_{CC}$ = 10.0 V; $V_I$ = $V_{IH}$ or $V_{IL}$ ; $ V_{SW} $ = $V_{CC}$ - GND; see Figure 8				
		per channel	-	-	±1.0	μΑ
S(ON)	ON-state leakage current	$V_{CC}$ = 10.0 V; $V_I$ = $V_{IH}$ or $V_{IL}$ ; $ V_{SW} $ = $V_{CC}$ - GND; see Figure 9	-	-	±1.0	μА
СС	supply current	$V_I = V_{CC}$ or GND; $V_{is} = GND$ or $V_{CC}$ ; $V_{os} = V_{CC}$ or GND				
		$V_{CC} = 6.0 \text{ V}$	-	-	20.0	μΑ
		V <sub>CC</sub> = 10.0 V	-	-	40.0	μΑ
Ç <sub>i</sub>	input capacitance		-	3.5	-	рF
S <sub>sw</sub>	switch capacitance		-	8	-	pF
amb = -40	0 °C to +125 °C					
/ <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	V
		$V_{CC} = 4.5 \text{ V}$	3.15	-	-	V
		$V_{CC} = 6.0 \text{ V}$	4.2	-	-	V
		V <sub>CC</sub> = 9.0 V	6.3	-	-	V
/ <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.50	V
		V <sub>CC</sub> = 4.5 V	-	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	-	1.80	V
		V <sub>CC</sub> = 9.0 V	-	-	2.70	V
l	input leakage current	$V_I = V_{CC}$ or GND				
		V <sub>CC</sub> = 6.0 V	-	-	±1.0	μΑ
		V <sub>CC</sub> = 10.0 V	-	-	±2.0	μΑ
S(OFF)	OFF-state leakage current	$V_{CC}$ = 10.0 V; $V_I$ = $V_{IH}$ or $V_{IL}$ ; $ V_{SW} $ = $V_{CC}$ - GND; see Figure 8				
		per channel	-	-	±1.0	μΑ
S(ON)	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW}  = V_{CC} - \text{GND}; \text{ see } \frac{\text{Figure 9}}{\text{Figure 9}}$	-	-	±1.0	μΑ
HC_HCT4066		All information provided in this document is subject to legal disclaimers.		1©	NXP B.V. 2013.	All rights res
roduct dat		Rev. 7 — 2 April 2013	-			7 o

#### Static characteristics 74HC4066 ...continued Table 7.

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).  $V_{is}$  is the input voltage at a Yn or Z terminal, whichever is assigned as an input. Vos is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
I <sub>CC</sub>	supply current	$\begin{aligned} &V_{l} = V_{CC} \text{ or GND; } V_{is} = \text{GND or } V_{CC}; \\ &V_{os} = V_{CC} \text{ or GND} \end{aligned}$				
		V <sub>CC</sub> = 6.0 V	-	-	40	μΑ
		V <sub>CC</sub> = 10.0 V	-	-	80	μΑ

<sup>[1]</sup> Typical values are measured at  $T_{amb} = 25$  °C.

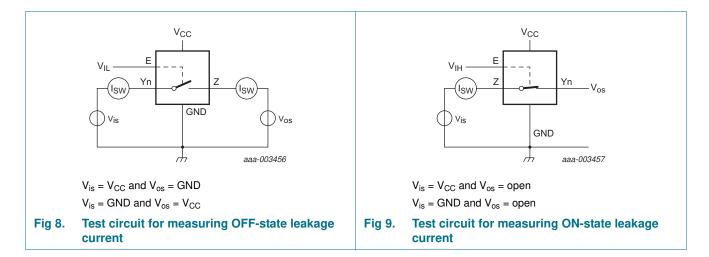
#### Static characteristics 74HCT4066

At recommended operating conditions; voltages are referenced to GND (ground = 0 V). V<sub>is</sub> is the input voltage at a Yn or Z terminal, whichever is assigned as an input.  $V_{os}$  is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
$T_{amb} = -40$	°C to +85 °C					
$V_{IH}$	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	1.6	-	V
$V_{IL}$	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	1.2	0.8	V
l <sub>l</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μΑ
I <sub>S(OFF)</sub>	OFF-state leakage current	$V_{CC} = 5.5 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW}  = V_{CC} - \text{GND}; \text{ see } \frac{\text{Figure 8}}{\text{Model}}$				
		per channel	-	-	±1.0	μΑ
I <sub>S(ON)</sub>	ON-state leakage current	$V_{CC} = 5.5 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW}  = V_{CC} - \text{GND}; \text{ see } \frac{\text{Figure 9}}{\text{Model}}$	-	-	±1.0	μΑ
I <sub>CC</sub>	supply current	$V_{I}$ = $V_{CC}$ or GND; $V_{is}$ = GND or $V_{CC}$ ; $V_{os}$ = $V_{CC}$ or GND; $V_{CC}$ = 4.5 V to 5.5 V	-	-	20.0	μΑ
$\Delta I_{CC}$	additional supply current	per input pin; $V_1 = V_{CC} - 2.1 \text{ V}$ ; other inputs at $V_{CC}$ or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V	-	100	450	μΑ
Cı	input capacitance		-	3.5	-	pF
C <sub>sw</sub>	switch capacitance		-	8	-	pF
$T_{amb} = -40$	°C to +125 °C					
$V_{IH}$	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	-	-	V
$V_{IL}$	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.8	V
I <sub>I</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μΑ
$I_{S(OFF)}$	OFF-state leakage current	$V_{CC} = 5.5 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW}  = V_{CC} - \text{GND}; \text{ see } \frac{\text{Figure 8}}{\text{Figure 8}}$				
		per channel	-	-	±1.0	μА
I <sub>S(ON)</sub>	ON-state leakage current	$V_{CC} = 5.5 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW}  = V_{CC} - \text{GND}; \text{ see } \frac{\text{Figure 9}}{\text{Figure 9}}$	-	-	±1.0	μΑ
I <sub>CC</sub>	supply current	$V_{I}$ = $V_{CC}$ or GND; $V_{is}$ = GND or $V_{CC}$ ; $V_{os}$ = $V_{CC}$ or GND; $V_{CC}$ = 4.5 V to 5.5 V		40	μА	
$\Delta I_{CC}$	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}$ ; other inputs at $V_{CC}$ or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V	-	-	490	μΑ

<sup>[1]</sup> Typical values are measured at  $T_{amb} = 25$  °C.

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### 10. Dynamic characteristics

#### Table 9. Dynamic characteristics 74HC4066

 $GND = 0 \ V$ ;  $t_r = t_f = 6 \ ns$ ;  $C_L = 50 \ pF$  unless specified otherwise; for test circuit see <u>Figure 12</u>.  $V_{is}$  is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

 $V_{os}$  is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions		-40	0 °C to +85	o°C	-40 °C to +125 °C		Unit
				Min	Typ[1]	Max	Min	Max	
t <sub>pd</sub>	propagation delay	nY to nZ or nZ to nY; $R_L = \infty \Omega$ ; see Figure 10	[2]			•			
		$V_{CC} = 2.0 \text{ V}$		-	8	75	-	90	ns
		$V_{CC} = 4.5 \text{ V}$		-	3	15	-	18	ns
		$V_{CC} = 6.0 \text{ V}$		-	2	13	-	15	ns
		$V_{CC} = 9.0 \text{ V}$		-	2	10	-	12	ns
t <sub>off</sub>	turn-off time	nE to nY or nZ; see Figure 11	[4]						
		$V_{CC} = 2.0 \text{ V}$		-	44	190	-	225	ns
		$V_{CC} = 4.5 \text{ V}$		-	16	38	-	45	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	13	-	-	-	ns
		$V_{CC} = 6.0 \text{ V}$		-	13	33	-	38	ns
		$V_{CC} = 9.0 \text{ V}$		-	16	26	-	30	ns
t <sub>on</sub>	turn-on time	nE to nY or nZ; see Figure 11	[3]						
		$V_{CC} = 2.0 \text{ V}$		-	36	125	-	150	ns
		$V_{CC} = 4.5 \text{ V}$		-	13	25	-	30	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	11	-	-	-	ns
		$V_{CC} = 6.0 \text{ V}$		-	10	21	-	26	ns
		$V_{CC} = 9.0 \text{ V}$		-	8	16	-	20	ns
C <sub>PD</sub>	power dissipation capacitance	per switch; $V_I = GND$ to $V_{CC}$	<u>[5]</u>	11		-	-	-	pF

<sup>[1]</sup> Typical values are measured at  $T_{amb}$  = 25 °C.

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**Product data sheet** 

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<sup>[2]</sup>  $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .

<sup>[3]</sup>  $t_{on}$  is the same as  $t_{PHZ}$  and  $t_{PLZ}$ .

[4] t<sub>off</sub> is the same as t<sub>PZH and</sub> t<sub>PZL</sub>.

[5]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$  where:

 $f_i$  = input frequency in MHz;

 $f_0$  = output frequency in MHz;

 $\sum \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\} = \text{sum of outputs};$ 

C<sub>L</sub> = output load capacitance in pF;

C<sub>sw</sub> = switch capacitance in pF;

V<sub>CC</sub> = supply voltage in V.

#### Table 10. Dynamic characteristics 74HCT4066

 $GND = 0 \ V; t_r = t_f = 6 \ ns; C_L = 50 \ pF \ unless \ specified \ otherwise; for test circuit see <u>Figure 12</u>.$ 

 $V_{is}$  is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

Vos is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions		-40	°C to +85	°C	-40 °C to	Unit	
				Min	Typ[1]	Max	Min	Max	
t <sub>pd</sub>	propagation delay	nY to nZ or nZ to nY; $R_L = \infty \Omega$ ; see Figure 10	[2]				'		'
		V <sub>CC</sub> = 4.5 V		-	3	15	-	18	ns
t <sub>off</sub>	turn-off time	nE to nY or nZ; see Figure 11	[4]						
		V <sub>CC</sub> = 4.5 V		-	20	44	-	53	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	16	-	-	-	ns
t <sub>on</sub>	turn-on time	nE to nY or nZ; see Figure 11	[3]						
		V <sub>CC</sub> = 4.5 V		-	12	30	-	36	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	12	-	-	-	ns
C <sub>PD</sub>	power dissipation capacitance	per switch; $V_I = GND$ to $(V_{CC} - 1.5 V)$	<u>[5]</u>	-	12	-	-	-	pF

<sup>[1]</sup> Typical values are measured at  $T_{amb} = 25$  °C.

[5]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

$$P_D = C_{PD} \times V_{CC}{}^2 \times f_i + \sum \{(C_L + C_{sw}) \times V_{CC}{}^2 \times f_o\}$$
 where:

 $f_i$  = input frequency in MHz;

 $f_o$  = output frequency in MHz;

$$\sum \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\} = sum \text{ of outputs};$$

 $C_L$  = output load capacitance in pF;

 $C_{sw}$  = switch capacitance in pF;

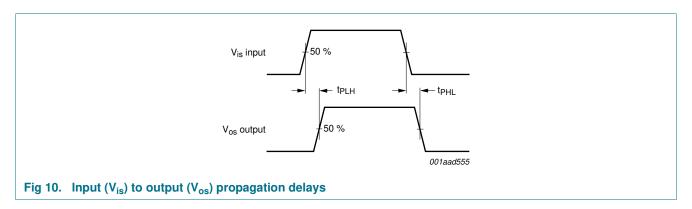
 $V_{CC}$  = supply voltage in V.

<sup>[2]</sup>  $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .

<sup>[3]</sup>  $t_{on}$  is the same as  $t_{PHZ}$  and  $t_{PLZ}$ .

<sup>[4]</sup>  $t_{off}$  is the same as  $t_{PZH}$  and  $t_{PZL}$ .

### 11. Waveforms



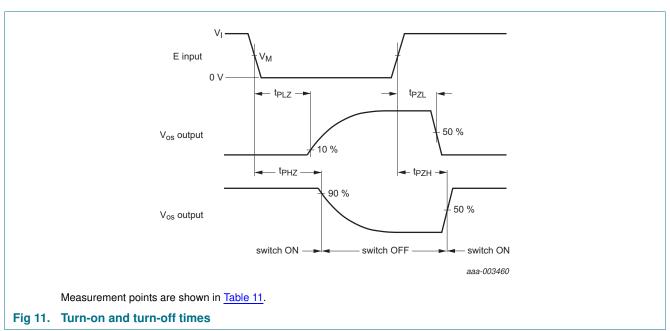
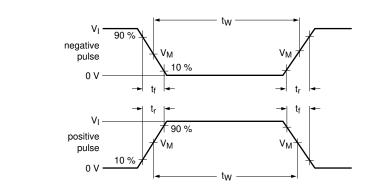
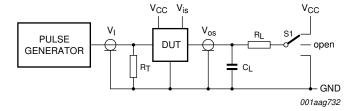


Table 11. Measurement points

Туре	V <sub>I</sub>	V <sub>M</sub>
74HC4066	V <sub>CC</sub>	0.5V <sub>CC</sub>
74HCT4066	3.0 V	1.3 V

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Test data is given in Table 12.

Definitions test circuit:

 $R_T$  = Termination resistance should be equal to output impedance  $Z_0$  of the pulse generator.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_L$  = Load resistor.

S1 = Test selection switch.

Fig 12. Load circuitry for measuring switching times

Table 12. Test data

Test	Input			Output	Output		
	Control E	Switch Yn (Z)	t <sub>r</sub> , t <sub>f</sub>	Switch Z (Yn)			
	V <sub>I</sub> [1]	V <sub>is</sub>		C <sub>L</sub>	R <sub>L</sub>		
t <sub>PHL</sub> , t <sub>PLH</sub>	GND	GND to V <sub>CC</sub>	6 ns	50 pF	-	open	
t <sub>PHZ</sub> , t <sub>PZH</sub>	GND to $V_{CC}$	V <sub>CC</sub>	6 ns	50 pF, 15 pF	1 kΩ	GND	
t <sub>PLZ</sub> , t <sub>PZL</sub>	GND to $V_{CC}$	GND	6 ns	50 pF, 15 pF	1 kΩ	V <sub>CC</sub>	

[1] For 74HCT4066: maximum input voltage  $V_I = 3.0 \text{ V}$ .

### 12. Additional dynamic characteristics

### Table 13. Additional dynamic characteristics

Recommended conditions and typical values; GND = 0 V; T<sub>amb</sub> = 25 °C.

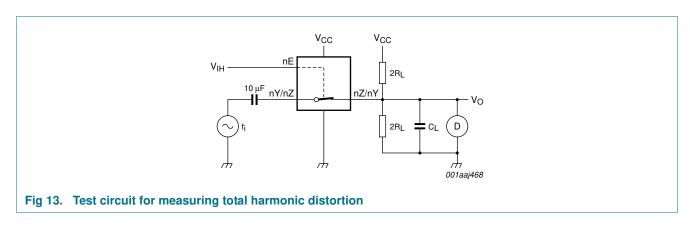
 $V_{is}$  is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

 $V_{os}$  is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
THD	total harmonic distortion	$f_i$ = 1 kHz; $R_L$ = 10 k $\Omega$ ; $C_L$ = 50 pF; see <u>Figure 13</u>				%
		$V_{CC} = 4.5 \text{ V}; V_I = 4.0 \text{ V (p-p)}$	-	0.04	-	%
		$V_{CC} = 9.0 \text{ V}; V_I = 8.0 \text{ V (p-p)}$	-	0.02	-	%
		$f_i$ = 10 kHz; $R_L$ = 10 k $\Omega$ ; $C_L$ = 50 pF; see Figure 13				
		$V_{CC} = 4.5 \text{ V}; V_I = 4.0 \text{ V (p-p)}$	-	0.12	-	%
		$V_{CC} = 9.0 \text{ V}; V_I = 8.0 \text{ V (p-p)}$	-	0.06	-	%
f <sub>(-3dB)</sub>	-3 dB frequency response	$R_L = 50 \Omega$ ; $C_L = 10 pF$ ; see Figure 15	[2]			
		V <sub>CC</sub> = 4.5 V	-	180	-	MHz
		$V_{CC} = 9.0 V$	-	200	-	MHz
$\alpha_{\text{iso}}$	isolation (OFF-state)	$R_L$ = 600 $\Omega$ ; $C_L$ = 50 pF; $f_i$ = 1 MHz; see Figure 14	[1]			
		$V_{CC} = 4.5 \text{ V}$	-	-50	-	dB
		$V_{CC} = 9.0 V$	-	-50	-	dB
V <sub>ct</sub>	crosstalk voltage	between digital input and switch (peak to peak value); $R_L = 600 \Omega$ ; $C_L = 50 pF$ ; $f_i = 1 MHz$ ; see Figure 16				
		V <sub>CC</sub> = 4.5 V	-	110	-	mV
		$V_{CC} = 9.0 \text{ V}$	-	220	-	mV
Xtalk	crosstalk	between switches; R <sub>L</sub> = 600 $\Omega$ ; C <sub>L</sub> = 50 pF; $f_i$ = 1 MHz; see Figure 17	[1]			
		V <sub>CC</sub> = 4.5 V	-	-60	-	dB
		$V_{CC} = 9.0 V$	-	-60	-	dB

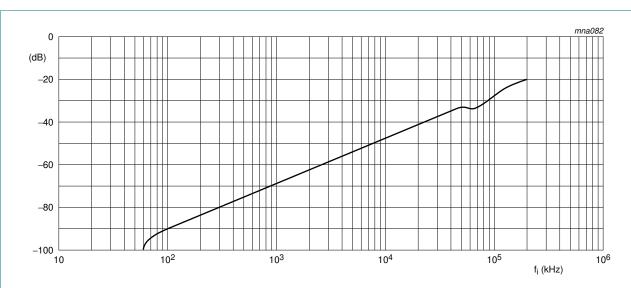
<sup>[1]</sup> Adjust input voltage  $V_{is}$  to 0 dBm level (0 dBm = 1 mW into 600  $\Omega$ ).

<sup>[2]</sup> Adjust input voltage V<sub>is</sub> to 0 dBm level at V<sub>os</sub> for f<sub>i</sub> = 1 MHz (0 dBm = 1 mW into 50 Ω). After set-up, f<sub>i</sub> is increased to obtain a reading of -3 dB at V<sub>os</sub>.

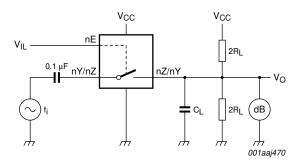


74HC\_HCT4066

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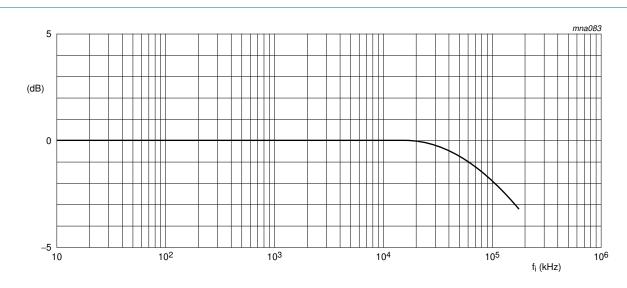
a. Isolation (OFF-state)



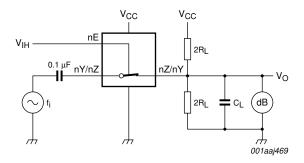
b. Test circuit

 $\mbox{V}_{\mbox{CC}}$  = 4.5 V; GND = 0 V;  $\mbox{R}_{\mbox{L}}$  = 600  $\Omega;$   $\mbox{R}_{\mbox{source}}$  = 1 k $\Omega.$ 

Fig 14. Isolation (OFF-state) as a function of frequency



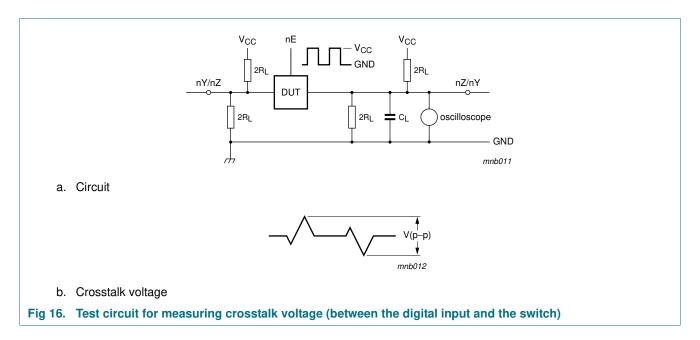
a. Typical -3 dB frequency response

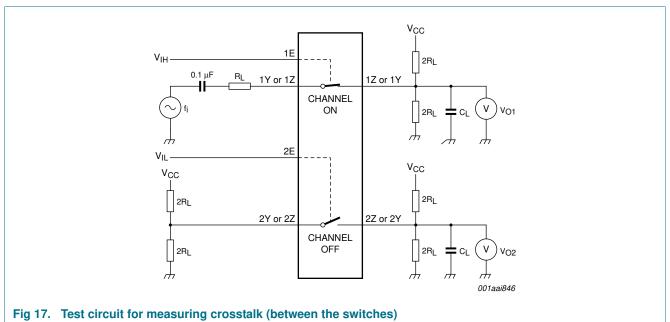


b. Test circuit

 $\mbox{V}_{\mbox{CC}}$  = 4.5 V; GND = 0 V;  $\mbox{R}_{\mbox{L}}$  = 50  $\Omega;$   $\mbox{R}_{\mbox{source}}$  = 1 k $\!\Omega.$ 

Fig 15. -3 dB frequency response



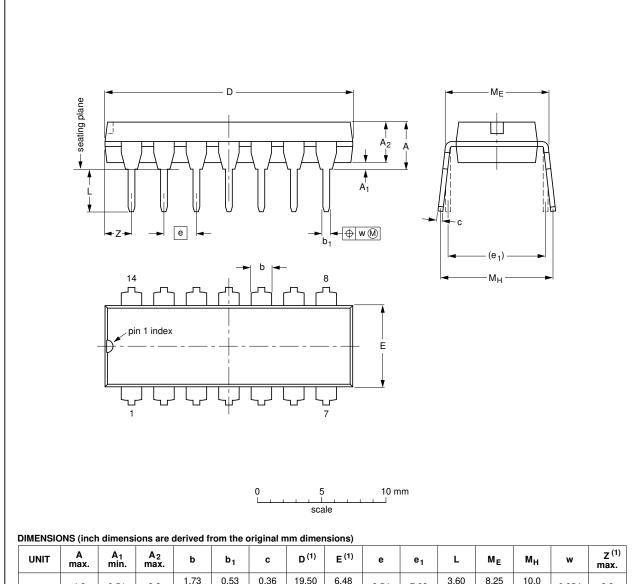


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### 13. Package outline

DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	С	D (1)	E <sup>(1)</sup>	е	e <sub>1</sub>	L	ME	Мн	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.02	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

#### Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

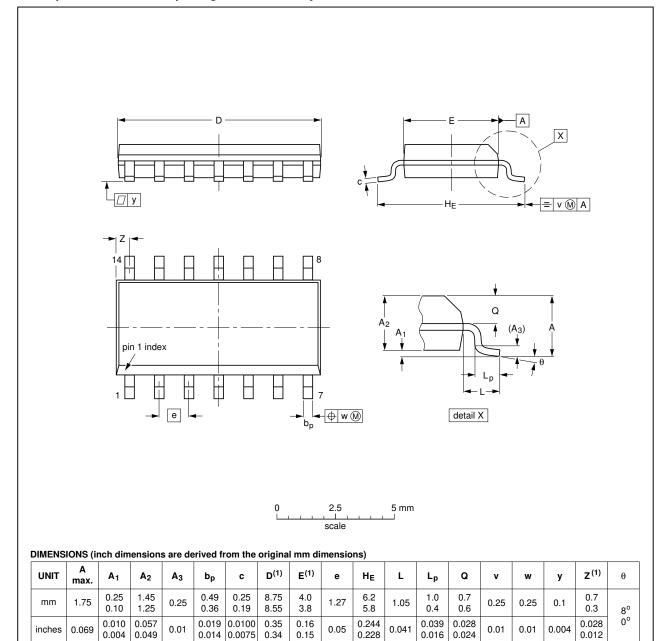
OUTLINE		EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT27-1	050G04	MO-001	SC-501-14			<del>99-12-27</del> 03-02-13

Fig 18. Package outline SOT27-1 (DIP14)

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SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



#### Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

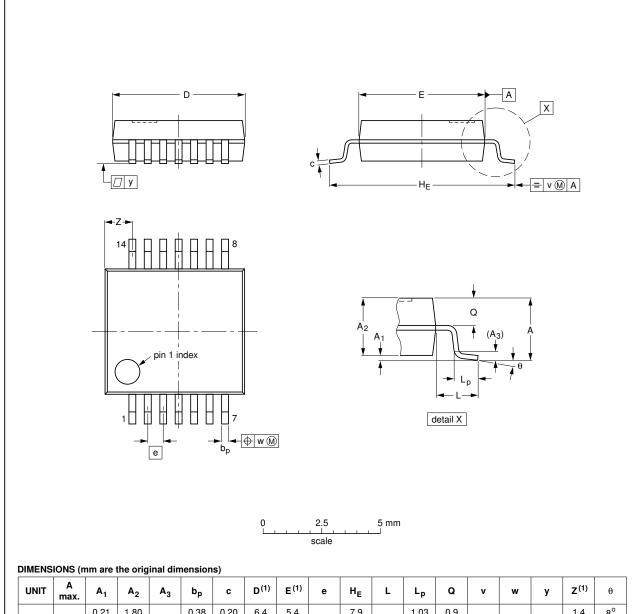
OUTLINE		EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT108-1	076E06	MS-012			<del>99-12-27</del> 03-02-19

Fig 19. Package outline SOT108-1 (SO14)

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SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



	Α																	
UNIT	max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	b <sub>p</sub>	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.4 0.9	8° 0°

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

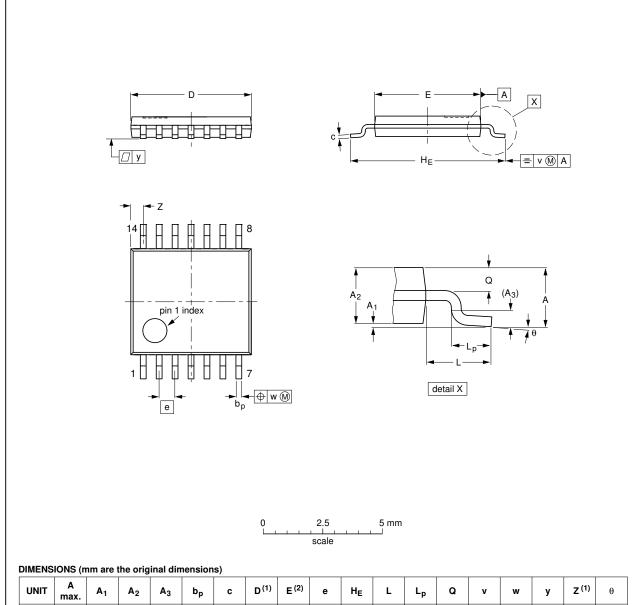
OUTLINE		EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT337-1		MO-150			<del>99-12-27</del> 03-02-19

Fig 20. Package outline SOT337-1 (SSOP14)

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TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



						-,												
UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E (2)	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
		OLITA		THOULDHON	
	MO-153				<del>99-12-27</del> 03-02-18
		MO-153	MO-153	MO-153	MO-153

Fig 21. Package outline SOT402-1 (TSSOP14)

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DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 x 3 x 0.85 mm SOT762-1

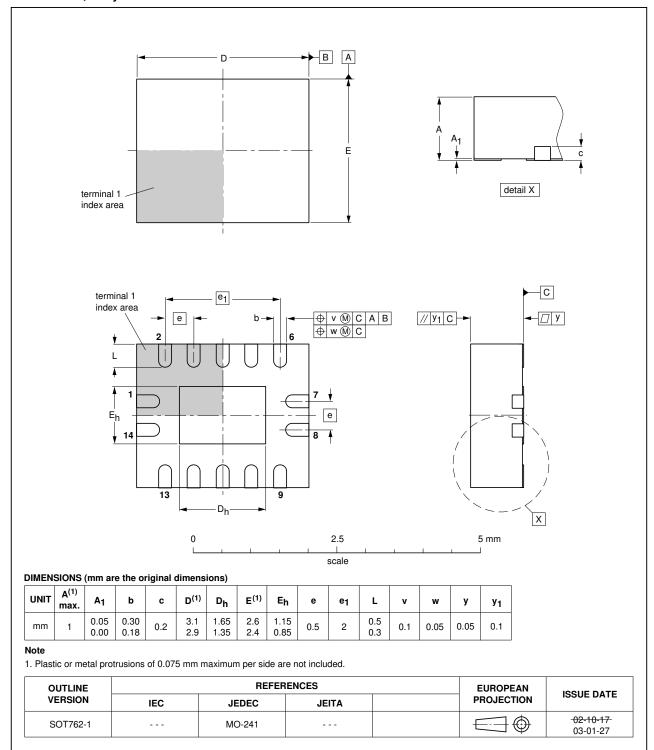


Fig 22. Package outline SOT762-1 (DHVQFN14)

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### 14. Abbreviations

### Table 14. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

## 15. Revision history

### Table 15. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT4066 v.7	20130402	Product data sheet	-	74HC_HCT4066 v.6
Modifications:	Descriptive ti	tle corrected (errata).		
	<ul> <li>New general</li> </ul>	description (errata).		
74HC_HCT4066 v.6	20120718	Product data sheet	-	74HC_HCT4066 v.5
Modifications:		f this data sheet has been rede NXP Semiconductors.	esigned to comply wi	ith the new identity
	<ul> <li>Legal texts have</li> </ul>	ave been adapted to the new o	company name wher	e appropriate.
74HC_HCT4066 v.5	20041111	Product data sheet	-	74HC_HCT4066 v.4
74HC_HCT4066 v.4	20030617	Product data sheet	-	74HC_HCT4066_CNV v.3
74HC_HCT4067_CNV v.3	19981110	Product data sheet	-	74HC_HCT4066_CNV v.2
74HC_HCT4066_CNV v.2	19981002	Product specification	-	-

### 16. Legal information

#### 16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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# 74HC4066; 74HCT4066

#### Quad single-pole single-throw analog switch

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